DIOTEC ELECTRONICS CORP. 18020 Hobart Blvd., Unit B Gardena, CA 90248 U.S.A

Tel.: (310) 767-1052 Fax: (310) 767-7958

1 AMP FAST RECOVERY SILICON DIODES

FEATURES

MECHANICAL SPECIFICATION

ACTUAL SIZE OF DO-41 PACKAGE

SERIES RP100 - RP110

Low cost

Low leakage

Low forward voltage drop

High current capacity

· Fast switching for high efficiency

MECHANICAL DATA

Case: JEDEC DO-41, molded plastic (U/L Flammability Rating 94V-0)

Terminals: Plated axial leads

Soldering: Per MIL-STD 202 Method 208 guaranteed

Polarity: Color band denotes cathode

Mounting Position: Any

• Weight: 0.012 Ounces (0.34 Grams)

DO - 41 LL BD (Dia) BL Color Band **Denotes** Cathode ш LD (Dia) -

Sym	Minimum		Maximum	
	ln	mm	ln	mm
BL	0.160	4.1	0.205	5.2
BD	0.103	2.6	0.107	2.7
LL	1.00	25.4		
LD	0.028	0.71	0.034	0.86

MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%. PARAMETER (TEST CONDITIONS) SYMBOL **RATINGS** UNITS **Series Number RP100 RP101** RP102 **RP104 RP106 RP108 RP110** Maximum DC Blocking Voltage 1000 **V**RM 50 100 200 400 600 800 Maximum RMS Voltage **V**RMS 35 280 420 **VOLTS** 140 Maximum Peak Recurrent Reverse Voltage **V**RRM 50 100 200 400 600 800 1000 Average Forward Rectified Current @ TA = 75°C 1 lo (Lead length = 0.375 in. (9.5 mm)) **AMPS** Peak Forward Surge Current (8.3 mSec single half sine wave **IFSM** 30 superimposed on rated load) Maximum Forward Voltage at 1 Amp DC Vғм 1.3 **VOLTS** Maximum Reverse Recovery Time (IF=0.5A, IR=1A, IRR=0.25A) TRR 150 250 500 (Note 3) nS @ $T_A = 25^{\circ}C$ Maximum Average DC Reverse Current 5 μA IRM At Rated DC Blocking Voltage @ $T_A = 100^{\circ}C$ 50 Typical Thermal Resistance, Junction to Ambient (Note 1) RθJA 50 °C/W **Typical Junction Capacitance (Note 2)** рF C.i 15 Operating and Storage Temperature Range TJ. TSTG -65 to +175 °C

NOTES: (1) Thermal resistance junction to ambient with diode mounted on PC Board and lead lengths = 0.375 in. (9.5 mm)

(2) Measured at 1MHz & applied reverse voltage of 4 volts (3) 300nS available - consult factory

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RATING & CHARACTERISTIC CURVES FOR SERIES RP100 - RP110

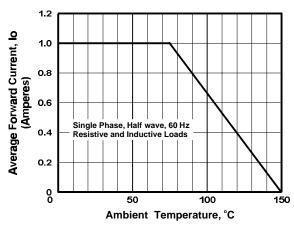


FIGURE 1. FORWARD CURRENT DERATING CURVE

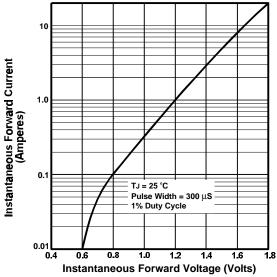
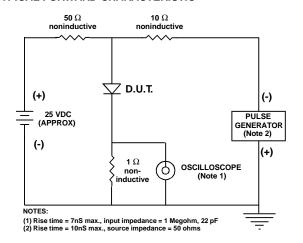


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC



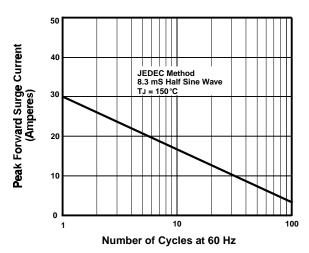


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

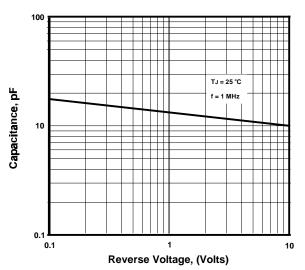


FIGURE 4. TYPICAL JUNCTION CAPACITANCE

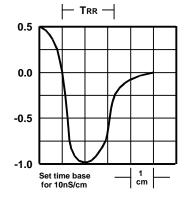


FIGURE 5. REVERSE RECOVERY TEST SETUP AND TIME CHARACTERISTIC